

# ZVNL120A

## N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

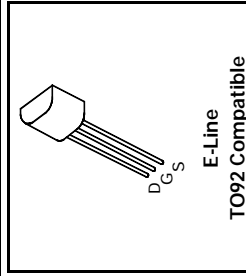
ISSUE 2 – MARCH 94

### FEATURES

- \* 200 Volt  $V_{DS}$
- \*  $R_{DS(on)} = 10\Omega$
- \* Low threshold

### APPLICATIONS

- \* Telephone handsets



### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	$V_{DS}$	200	V
Continuous Drain Current at $T_{amb}=25^\circ\text{C}$	$I_D$	180	mA
Pulsed Drain Current	$I_{DM}$	2	A
Gate Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation at $T_{amb}=25^\circ\text{C}$	$P_{tot}$	700	mW
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 to +150	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

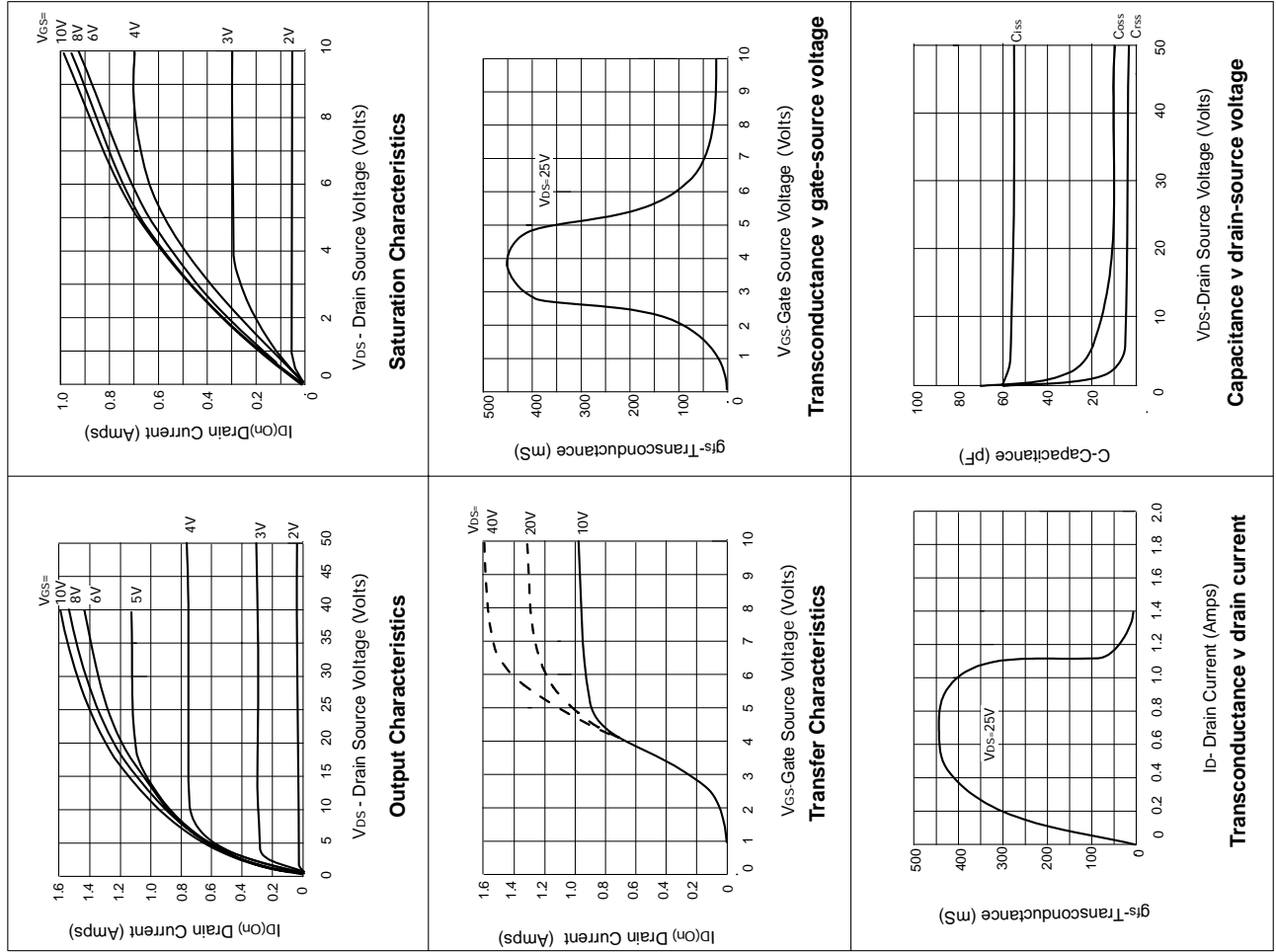
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	$BV_{DSS}$	200		V	$I_D = 1\text{mA}, V_{GS} = 0\text{V}$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.5	1.5	V	$I_D = 1\text{mA}, V_{DS} = V_{GS}$
Gate-Body Leakage	$I_{GSS}$		100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
Zero Gate Voltage Drain Current	$I_{DSS}$		10	$\mu\text{A}$	$V_{DS} = 200\text{V}, V_{GS} = 0$
			100	$\mu\text{A}$	$V_{DS} = 160\text{V}, V_{GS} = 0\text{V}, T = 125^\circ\text{C}(2)$
On-State Drain Current(1)	$I_{D(on)}$	500		mA	$V_{DS} = 25\text{V}, V_{GS} = 5\text{V}$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		10	$\Omega$	$V_{GS} = 5\text{V}, I_D = 250\text{mA}$
			10	$\Omega$	$V_{GS} = 3\text{V}, I_D = 125\text{mA}$
Forward Transconductance (1)(2)	$g_{fs}$	200		mS	$V_{DS} = 25\text{V}, I_D = 250\text{mA}$
Input Capacitance (2)	$C_{iss}$		85	pF	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
Common Source Output Capacitance (2)	$C_{oss}$		20	pF	
Reverse Transfer Capacitance (2)	$C_{rss}$		7	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		8	ns	
Rise Time (2)(3)	$t_r$		8	ns	$V_{DD} = 25\text{V}, I_D = 250\text{mA}$
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		20	ns	
Fall Time (2)(3)	$t_f$		12	ns	

(1) Measured under pulsed conditions. Width=300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$  (2) Sample test.

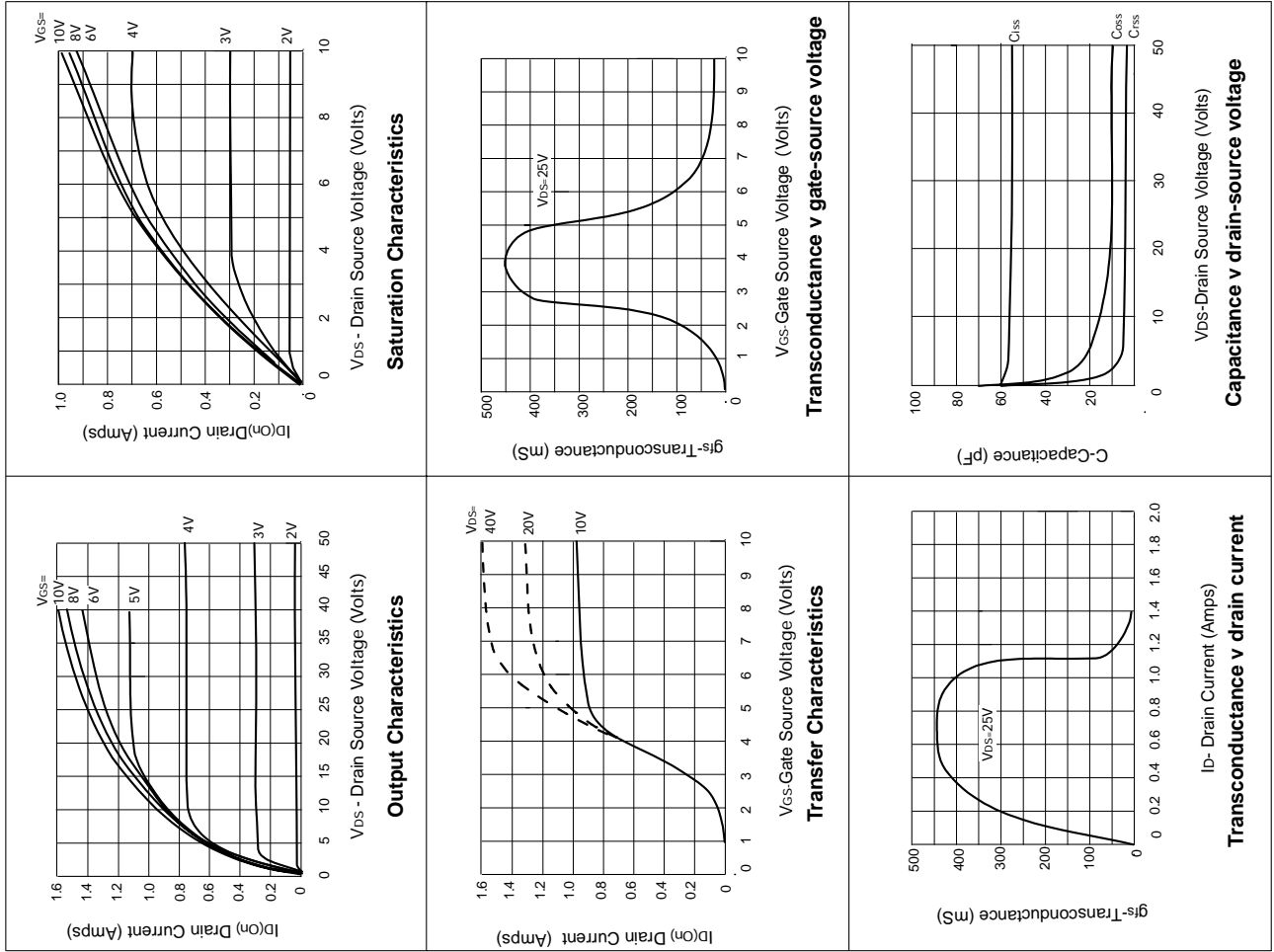
(3) Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator

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## TYPICAL CHARACTERISTICS



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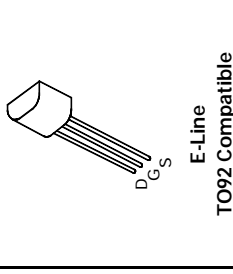


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ELECTRICAL CHARACTERISTICS (at  $T_{amb} = 25^{\circ}C$  unless otherwise stated).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	$BV_{DSS}$	200		V	$I_D = 1mA, V_{GS} = 0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.5	1.5	V	$I_D = 1mA, V_{DS} = V_{GS}$
Gate-Body Leakage	$I_{GSS}$		100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
Zero Gate Voltage Drain Current	$I_{DSS}$		10	$\mu A$	$V_{DS} = 200V, V_{GS} = 0$
			100	$\mu A$	$V_{DS} = 160V, V_{GS} = 0V, T = 125^{\circ}C(2)$
On-State Drain Current(1)	$I_{D(on)}$	500		mA	$V_{DS} = 25V, V_{GS} = 5V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		10	$\Omega$	$V_{GS} = 5V, I_D = 250mA$
			10	$\Omega$	$V_{GS} = 3V, I_D = 125mA$
Forward Transconductance (1)(2)	$g_{fs}$	200		mS	$V_{DS} = 25V, I_D = 250mA$
Input Capacitance (2)	$C_{iss}$		85	pF	
Common Source Output Capacitance (2)	$C_{oss}$		20	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$
Reverse Transfer Capacitance (2)	$C_{rss}$		7	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		8	ns	
Rise Time (2)(3)	$t_r$		8	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		20	ns	
Fall Time (2)(3)	$t_f$		12	ns	$V_{DD} = 25V, I_D = 250mA$

(1) Measured under pulsed conditions. Width=300 $\mu s$ . Duty cycle  $\leq 2\%$  (2) Sample test.

(3) Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator

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